## **AMENDMENTS TO THE CLAIMS:**

This listing of claims will replace all prior versions and listings of claims in the application:

1. (presently amended) A light-emissive device comprising:

a light-emissive region;

a first electrode located on a viewing side of the light-emissive region for injecting charge carriers of a first type; and

a second electrode located on a non-viewing side of the light-emissive region for injecting charge carriers of a second type;

and wherein there is a reflectivity-influencing structure located on the non-viewing side of the light-emissive region and including a light absorbent layer comprising graphite and/or a fluoride or oxide of a low work function metal a fluoride or oxide of a metal having a work function of 3.5 eV or less.

- 2. (original) A light-emissive device as claimed in claim 1, wherein the first electrode is at least partially light-transmissive.
- 3. (previously amended) A light-emissive device as claimed in claim 1, wherein the reflectivity influencing structure is located on the opposite side of the second electrode from the light-emissive region.

4. (original) A light-emissive device as claimed in claim 3, wherein the second electrode is at least partially light-transmissive.
5. (previously amended) A light-emissive device as claimed in claim 3, wherein the thickness of the second electrode is less than 30nm.
6. (previously amended) A light-emissive device as claimed in claim 3, wherein the reflectivity-influencing structure is adjacent the second electrode.
7. (previously amended) A light-emissive device as claimed in claim 1, wherein the second electrode provides the reflectivity-influencing structure.
8. (original) A light-emissive device as claimed in claim 7, wherein the second electrode comprises a fluoride or oxide of a low work function metal.
9. (original) A light-emissive device as claimed in claim 8, wherein the second electrode comprises aluminium.

- 10. (previously amended) A light-emissive device as claimed in claim 1, wherein the reflectivity-influencing structure is effective to absorb light emitted from the light-emissive region that reaches it through the second electrode and/or incident light.
- 11. (previously amended) A light-emissive device as claimed in claim 7, wherein the presence of the reflectivity-influencing structure adjacent the second electrode renders that second electrode substantially non-reflective to light emitted form the light-emissive region and/or incident light.
- 12. (previously amended) A light-emissive device as claimed in claim 1, wherein the second electrode comprises an electrically conductive material.
- 13. (presently amended) A light-emissive device as claimed in claim 1, wherein the light-emissive layer region comprises an organic light-emissive material.
- 14. (presently amended) A light-emissive device as claimed in claim 1, wherein the light-emissive layer region comprises a polymer light-emissive material.

- 15. (presently amended) A light-emissive device as claimed in claim 1, wherein the light-emissive layer region comprises a conjugated polymer material.
- 16. (presently amended) A light-emissive device as claimed in claim 1, wherein the reflecten vity-influencing r is electrically conductive.
- 17.-27. (canceled)
- 28. (presently amended) A light-emissive device as claimed in claim 26, A light-emissive device comprising:

a light-emissive region;

a first electrode located on a viewing side of the light-emissive region for injecting charge carriers of a first type;

a second electrode located on a non-viewing side of the light-emissive region for injecting charge carriers of a second type;

and a contrast enhancing structure located on the non-viewing side of the lightemissive region and including a reflective structure having different reflectivity for
different wavelengths of incident light, and having a reflectivity peak encompassing an
emission wavelength of the light-emissive region,

wherein the second electrode comprises a layer located on the non-viewing side of the reflective structure and a plurality of through paths passing through the reflective structure for electrical conduction between the said layer of the second electrode and the light-emissive region.

- 29. (original) A light-emissive device as claimed in claim 28, wherein the though paths occupy less than 15% of the emissive area of the device.
- 30. (canceled)
- 31. (presently amended) A light-emissive device as claimed in claim 30 28, wherein the second electrode comprises a transparent layer located between the reflective structure and the light-emissive region, and the transparent layer is in contact with the through paths.
- 32.-34. (canceled)
- 35. (presently amended) A light-emissive device as claimed in claim 26 28, wherein the light-emissive layer region comprises a conjugated polymer material.

Please grant any extensions of time required to enter this response and charge any additional required fees to our deposit account 06-0916.

Respectfully submitted,

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Oct 22, 2003

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